NPN PRE-BIASED SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Built-In Biasing Resistors, R1 Only
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High-Reliability
- PPAP Capable (Note 4)

R₁ (NOM) $1k\Omega$

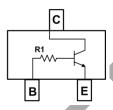
SOT23



Top View

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)



Device Schematic - Top View

Ordering Information (Note 5)

Product	Compliance	Marking	Re	el Size (incl	hes)	Tape \	Width (mm)	Quantity per Ree
ADTC113TCAQ-7	Automotive	2F4		7	_		8	3,000
ADTC113TCAQ-13	Automotive	2F4		13			8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT23

2F4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018)

M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	202	2 20)23	2024		2025	2026	2027	2028
Code	F	G	Н		J		K	L		M	N	0	Р
Month	Jan	Feb	Mar	Apr	May	Jun	Ju	1 /	Aug	Sep	Oct	Nov	Dec
Code		2	3	4	5	6	7		8	9	0	N	D



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I _C (Max)	100	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

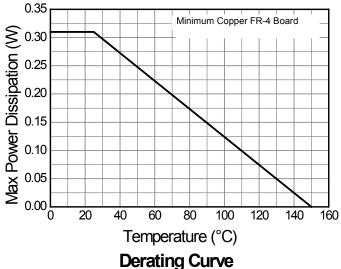
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_{D}	310	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	403	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

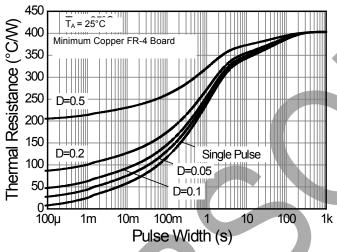
Note: 6. Mounted on FR4 PC Board with minimum recommended pad layout.



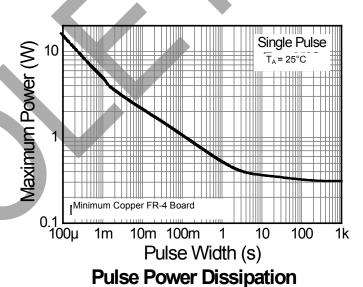


Thermal Characteristics and Derating Information





Transient Thermal Impedance

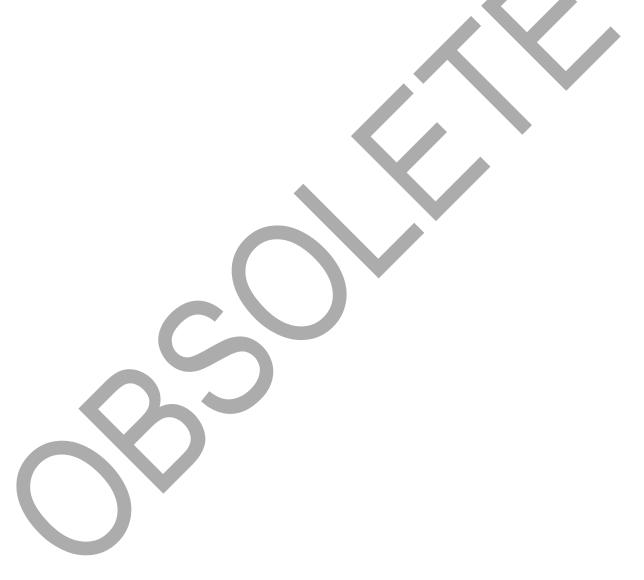




Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

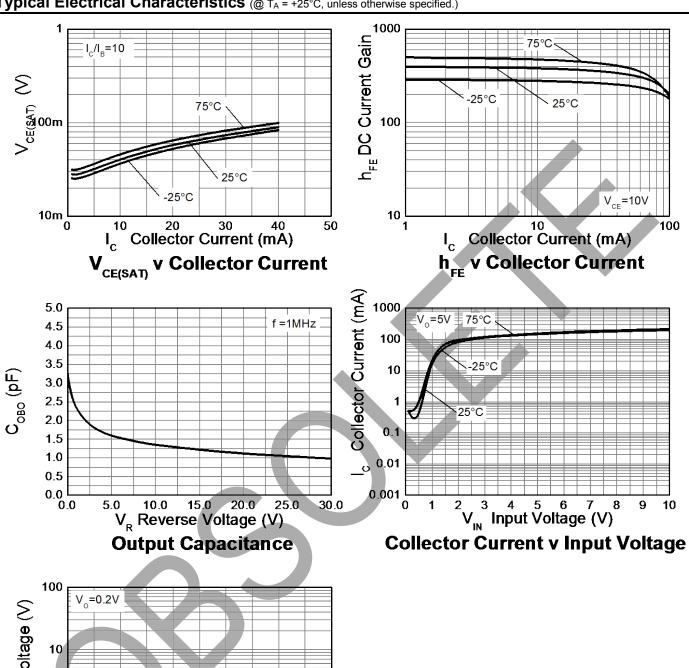
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	_		V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	_	_	V	I _E = 50μA
Collector Cutoff Current	I _{CBO}	_	_	0.5	μΑ	V _{CB} = 50V
Emitter Cutoff Current	I _{EBO}	_	_	0.5	μΑ	V _{EB} = 4V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	0.3	V	$I_{C}/I_{B} = 10\text{mA}/1\text{mA}$
DC Current Transfer Ratio	h _{FE}	100	250	600	_	$I_C = 1mA$, $V_{CE} = 5V$
Input Resistor (R ₁) Tolerance	ΔR_1	-30	_	+30	%	_
Gain-Bandwidth Product (Note 7)	f⊤		250		MHz	$V_{CE} = 10V$, $I_{E} = 5mA$, $f = 100MHz$

Note: 7. Transistor - For Reference Only.





Typical Electrical Characteristics (@ TA = +25°C, unless otherwise specified.)



V_{IN} Input Voltage (V) 25°C 75°C 0.1 20 30 40 Collector Current (mA) 50

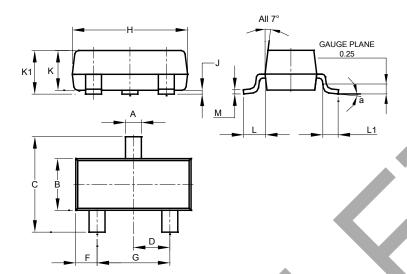
Input Voltage v Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

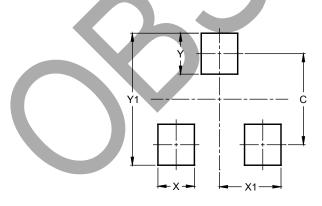


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
H	2.80	3.00	2.90			
7	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°	_			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)				
С	2.0				
X	0.8				
X1	1.35				
Y	0.9				
V1	2.0				



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